


STANDARD RECOVERY DIODES

MAGN-A-pak™ Power Modules

Features

- High voltage
- Electrically isolated base plate
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL E78996 approved 

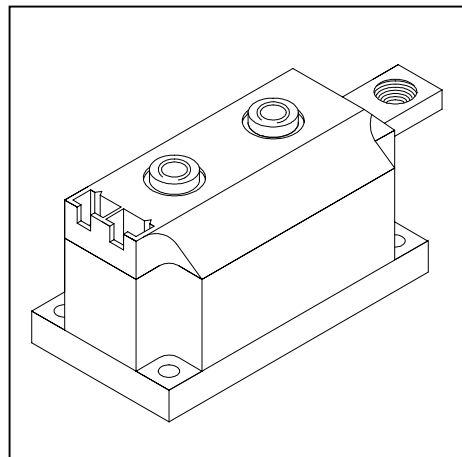
250A
270A
320A

Description

This new IRK series of MAGN-A-paks uses high voltage power diodes in two basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges and the single diode module can be used in conjunction with the thyristor modules as a freewheel diode. These modules are intended for general purpose applications such as battery chargers, welders and plating equipment and where high voltage and high current are required (motor drives, etc.).

Major Ratings and Characteristics

Parameters	IRK.250..	IRK.270..	IRK.320..	Units
$I_{F(AV)}$	250	270	320	A
@ T _C	100	100	100	°C
$I_{F(RMS)}$	393	424	502	A
I_{FSM} @ 50Hz	7015	8920	10110	A
@ 60Hz	7345	9430	10580	A
I^2t @ 50Hz	246	398	511	KA ² s
@ 60Hz	225	363	466	KA ² s
$I^2\sqrt{t}$	2460	3980	5110	KA ² √s
V _{RRM}	Up to 2000	Up to 3000	Up to 2000	V
T _J	-40 to 150			°C



ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , Maximum repetitive peak reverse voltage V	V_{RSM} , Maximum non-repetitive peak reverse voltage V	I_{RRM} Max @ 150°C mA
IRK.250- IRK.270- IRK.320-	04	400	500	50
	08	800	900	
	12	1200	1300	
	16	1600	1700	
IRK.320-	20	2000	2100	50
	24	2400	2500	
	30	3000	3100	

Forward Conduction

Parameters	IRK.250	IRK.270	IRK.320	Units	Conditions		
$I_{F(AV)}$ Maximum average forward current @ Case temperature	250	270	320	A	180° conduction, half sine wave		
	100	100	100	°C			
$I_{F(RMS)}$ Maximum RMS forward current	393	424	502	A	as AC switch		
I_{FSM} Maximum peak, one-cycle forward, non-repetitive surge current	7015	8920	10110	A	t = 10ms	No voltage reappplied	Sinusoidal half wave, Initial $T_J = T_{J,max}$
	7345	9340	10580		t = 8.3ms	reappplied	
	5900	7500	8500		t = 10ms	100% V_{RRM} reappplied	
	6180	7850	8900		t = 8.3ms	reappplied	
I^2t Maximum I^2t for fusing	246	398	511	KA ² s	t = 10ms	No voltage reappplied	Initial $T_J = T_{J,max}$
	225	363	466		t = 8.3ms	reappplied	
	174	281	361		t = 10ms	100% V_{RRM} reappplied	
	159	257	330		t = 8.3ms	reappplied	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	2460	3980	5110	KA ² √s	t = 0.1 to 10ms, no voltage reappplied		
$V_{F(TO)1}$ Low level val. of threshold voltage	0.79	0.74	0.69	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_{J,max}$.		
$V_{F(TO)2}$ High level val. of threshold voltage	0.92	0.87	0.86	V	$(I > \pi \times I_{F(AV)})$, $T_J = T_{J,max}$.		
r_{T1} Low level forward slope resistance	0.63	0.94	0.59	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_{J,max}$.		
r_{T2} High level forward slope resistance	0.49	0.81	0.44	mΩ	$(I > \pi \times I_{F(AV)})$, $T_J = T_{J,max}$.		
V_{FM} Maximum forward voltage drop	1.29	1.48	1.28	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = T_{J,max}$, 180° conduction Av. power = $V_{F(TO)} \times I_{F(AV)} + r_T \times (I_{F(RMS)})^2$		

Blocking

Parameter	IRK.250/.270/.320	Units	Conditions
I_{RRM} Max. peak reverse leakage current	50	mA	$T_J = 150^\circ\text{C}$
V_{INS} RMS isolation voltage	3000	V	50Hz, circuit to base, all terminals shorted, t=1sec

Thermal and Mechanical Specifications

Parameter	IRK.250 / .270 / .320	Units	Conditions
T _J Max. junction operating temperature range	-40 to 150	°C	
T _{stg} Max. storage temperature range	-40 to 150	°C	
R _{thJC} Max. thermal resistance, junction to case	0.16 0.125 0.125	K/W	Per junction, DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.035	K/W	Mounting surface flat, smooth and greased Per module
T Mounting torque ±10% MAP to heatsink busbar to MAP	4 to 6 8 to 10	Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound
wt Approximate weight	800 (30)	g (oz)	

ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T _J max.					Rectangular conduction @ T _J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.250-	0.009	0.010	0.014	0.020	0.032	0.007	0.011	0.015	0.021	0.033	K/W
IRK.270-	0.008	0.012	0.014	0.020	0.032	0.007	0.011	0.015	0.020	0.033	
IRK.320-	0.008	0.010	0.013	0.020	0.032	0.007	0.011	0.015	0.020	0.033	

Ordering Information Table

Device Code

IRK

D

320

-

24

①

②

③

④

- 1 - Module type
- 2 - Circuit configuration
- 3 - Current rating: I_{F(AV)} x 10 rounded
- 4 - Voltage code: Code x 100 = V_{RRM} (see Voltage Rating Table)

Outline Table

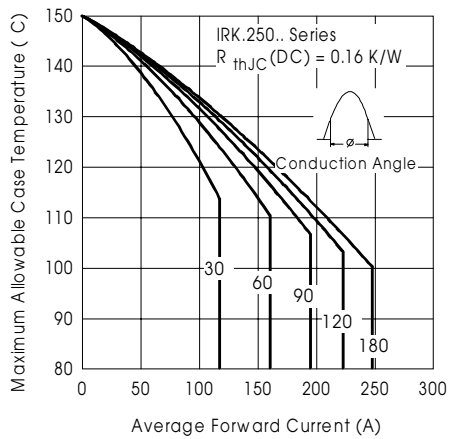
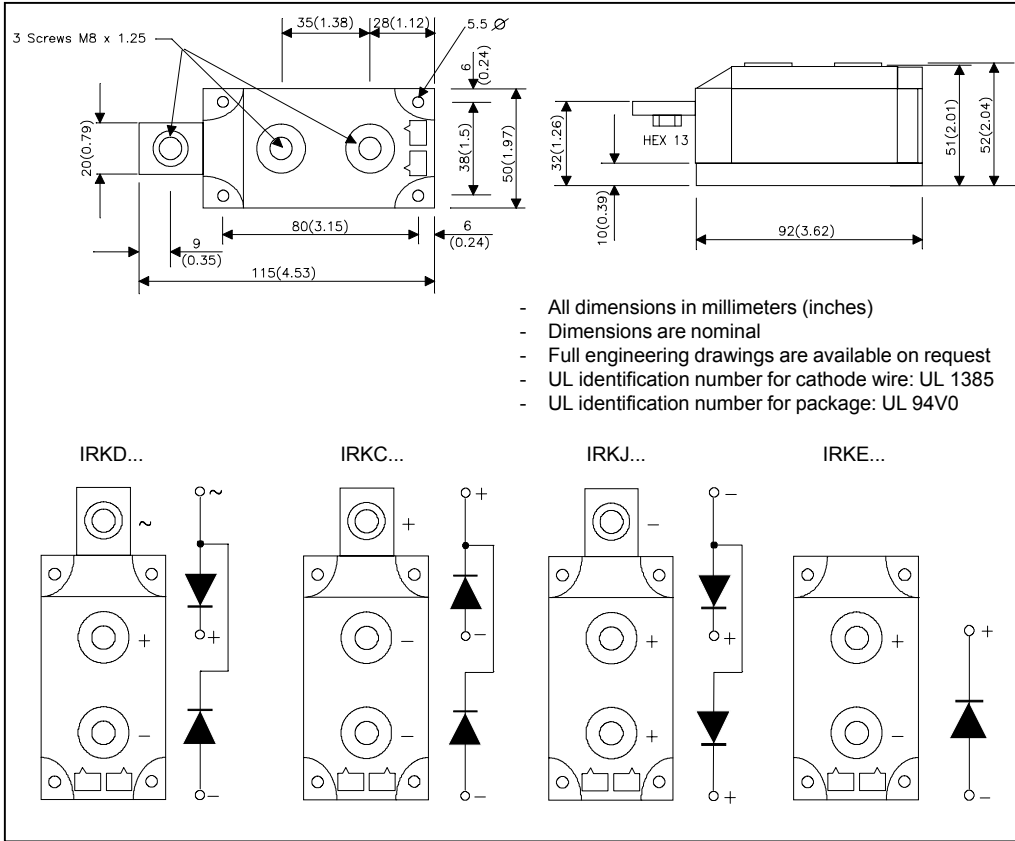


Fig. 1 - Current Ratings Characteristics

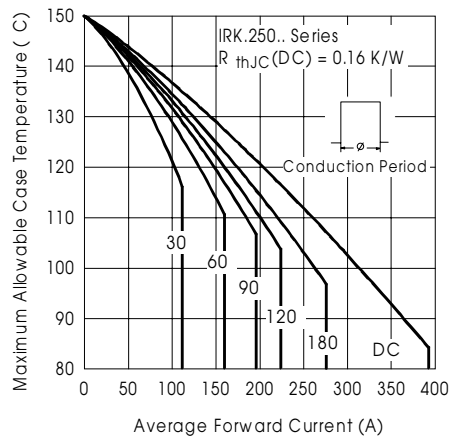


Fig. 2 - Current Ratings Characteristics

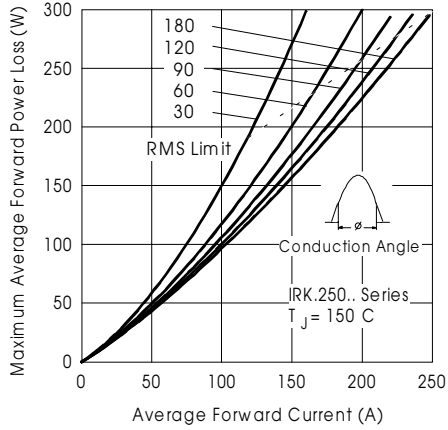


Fig. 3 - Forward Power Loss Characteristics

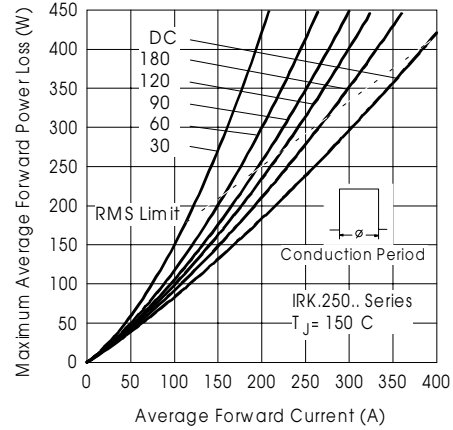


Fig. 4 - Forward Power Loss Characteristics

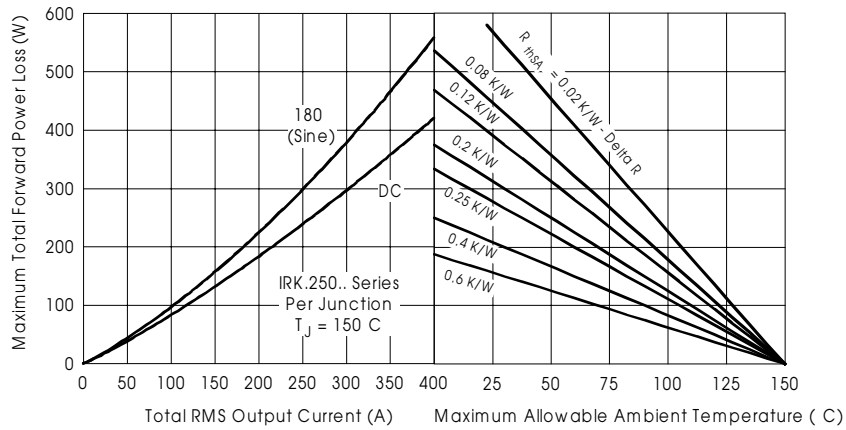


Fig. 5 - Forward Power Loss Characteristics

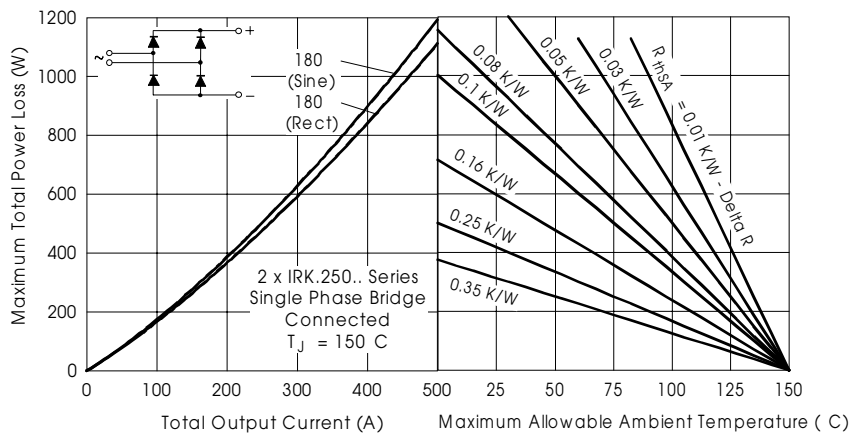


Fig. 6 - Forward Power Loss Characteristics

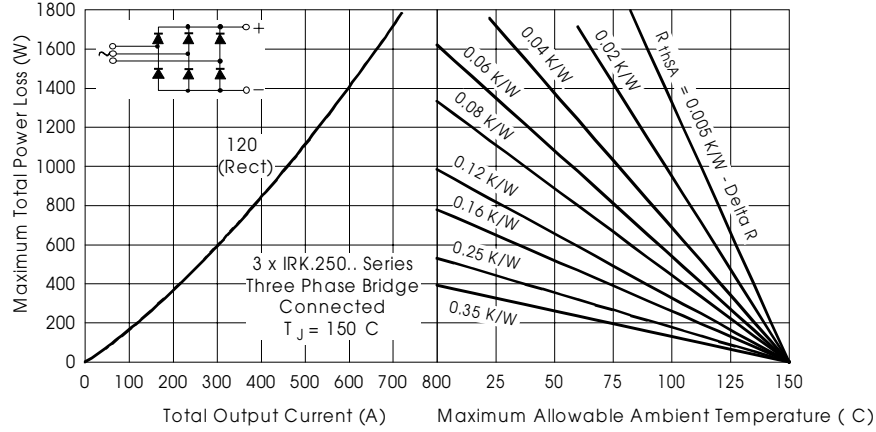


Fig. 7 - Forward Power Loss Characteristics

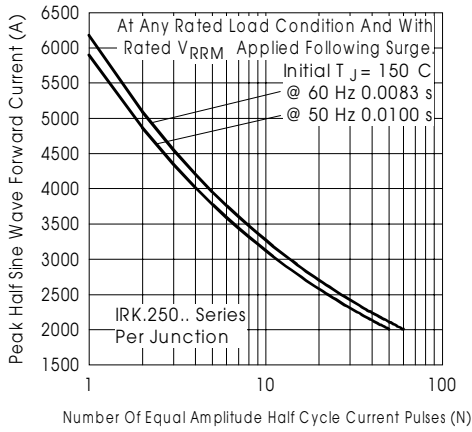


Fig. 8 - Maximum Non-Repetitive Surge Current

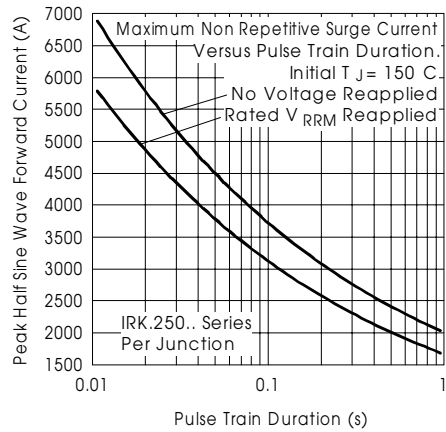


Fig. 9 - Maximum Non-Repetitive Surge Current

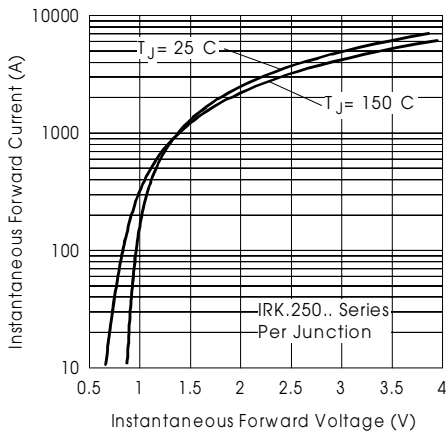


Fig. 10 - Forward Voltage Drop Characteristics

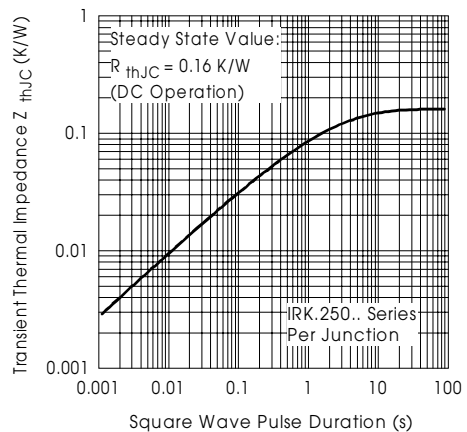


Fig. 11 - Thermal Impedance $Z_{\theta JC}$ Characteristics

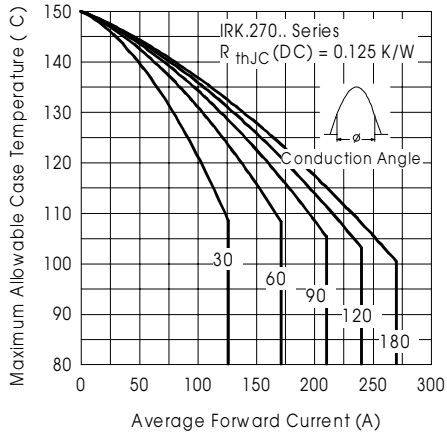


Fig. 12 - Current Ratings Characteristics

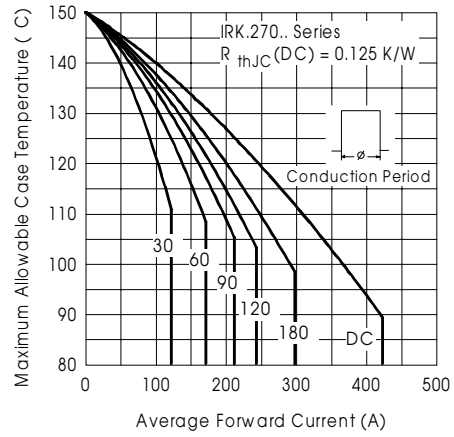


Fig. 13 - Current Ratings Characteristics

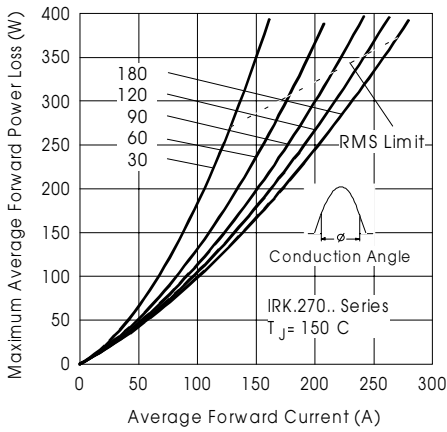


Fig. 14 - Forward Power Loss Characteristics

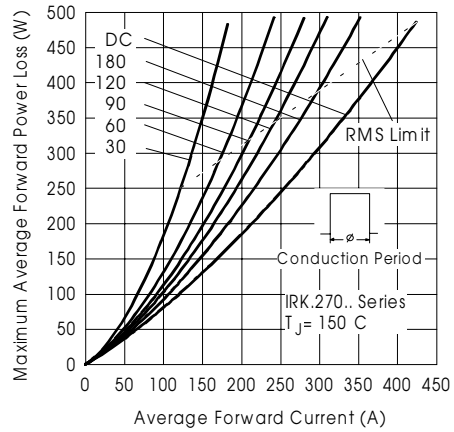


Fig. 15 - Forward Power Loss Characteristics

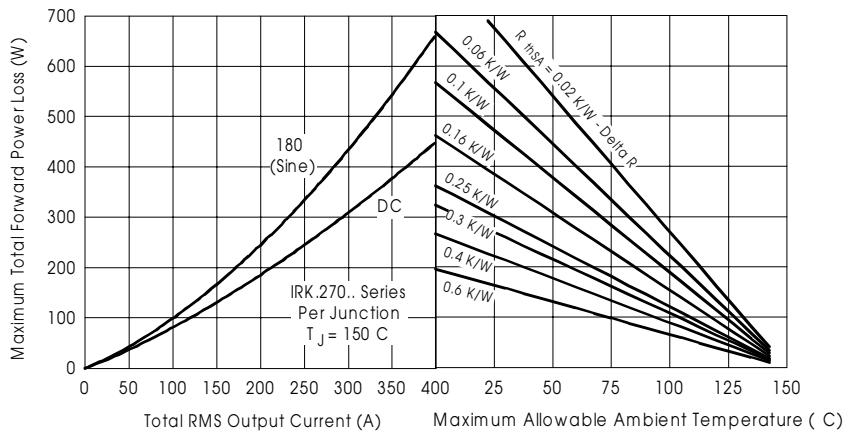


Fig. 16 - Forward Power Loss Characteristics

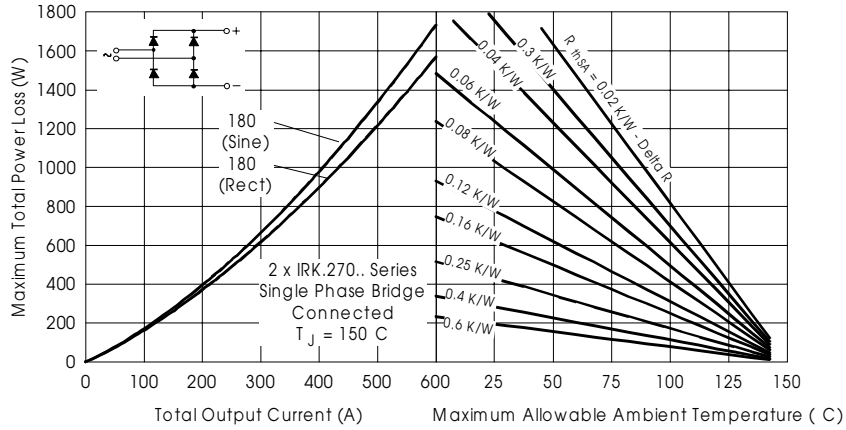


Fig. 17 - Forward Power Loss Characteristics

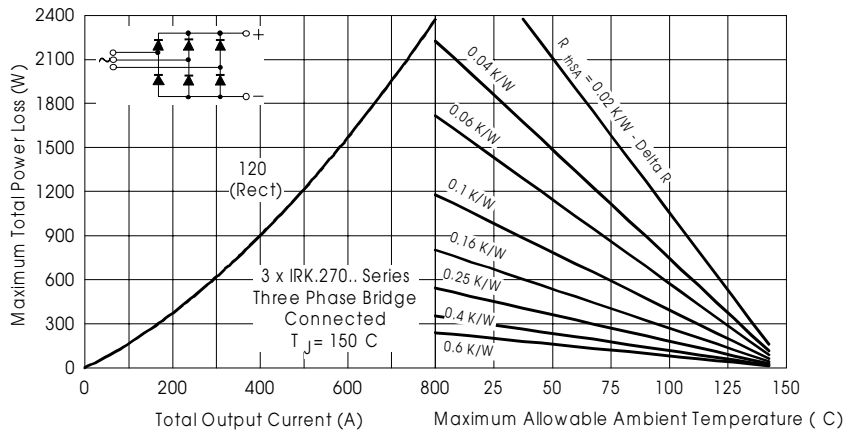


Fig. 18 - Forward Power Loss Characteristics

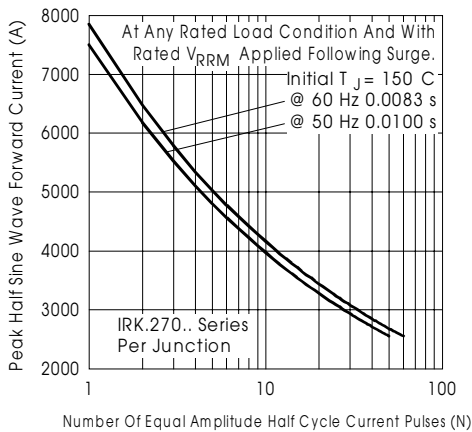


Fig. 19 - Maximum Non-Repetitive Surge Current

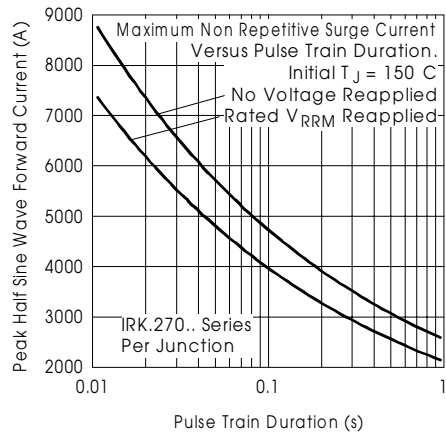


Fig. 20 - Maximum Non-Repetitive Surge Current

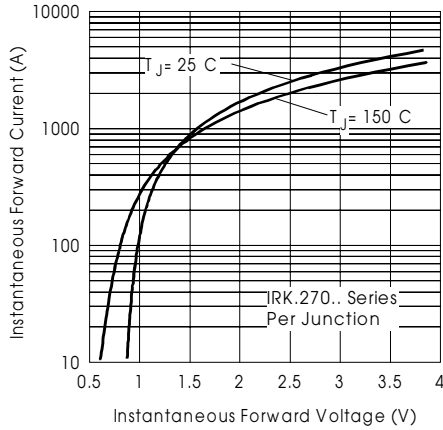


Fig. 21 - Forward Voltage Drop Characteristics

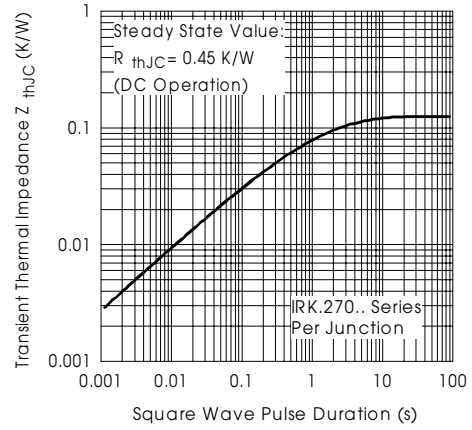


Fig. 22 - Thermal Impedance Z_{thJC} Characteristics

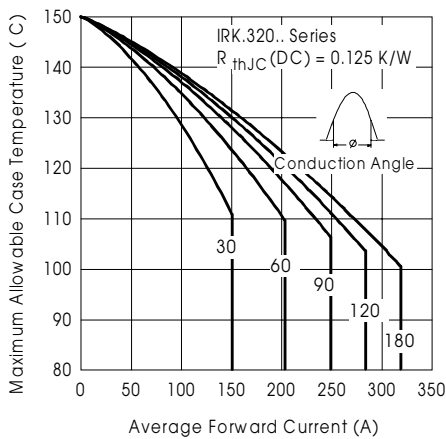


Fig. 23 - Current Ratings Characteristics

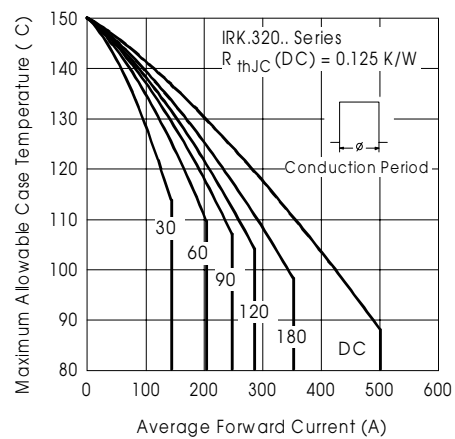


Fig. 24 - Current Ratings Characteristics

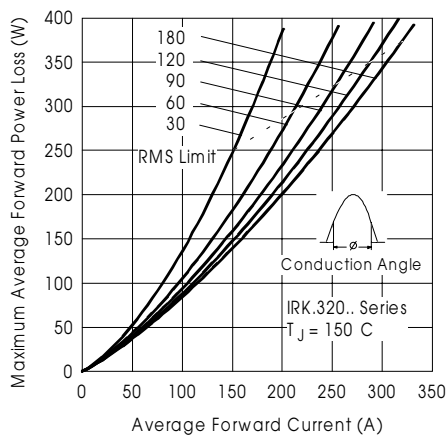


Fig. 25 - Forward Power Loss Characteristics

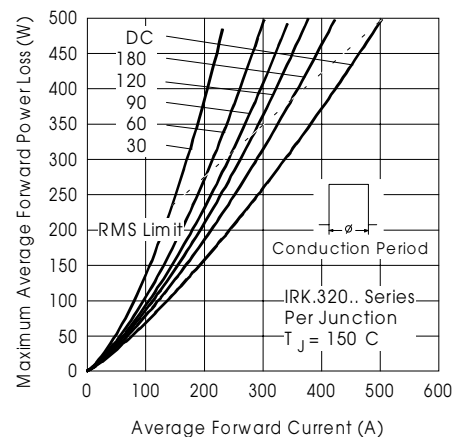


Fig. 26 - Forward Power Loss Characteristics

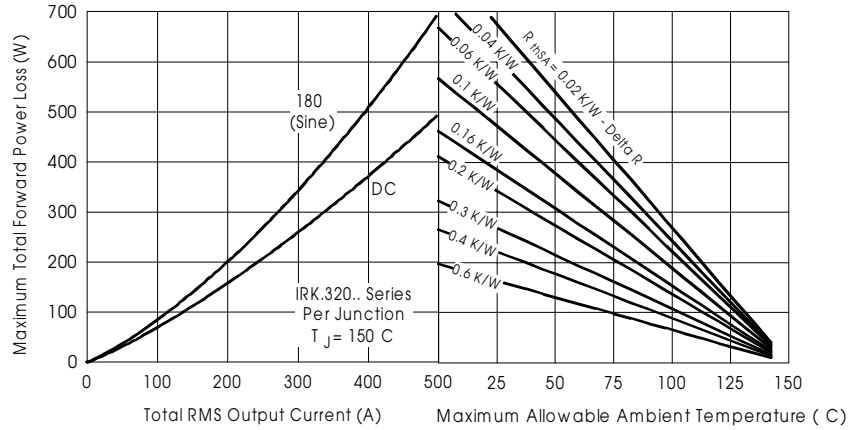


Fig. 27 - Forward Power Loss Characteristics

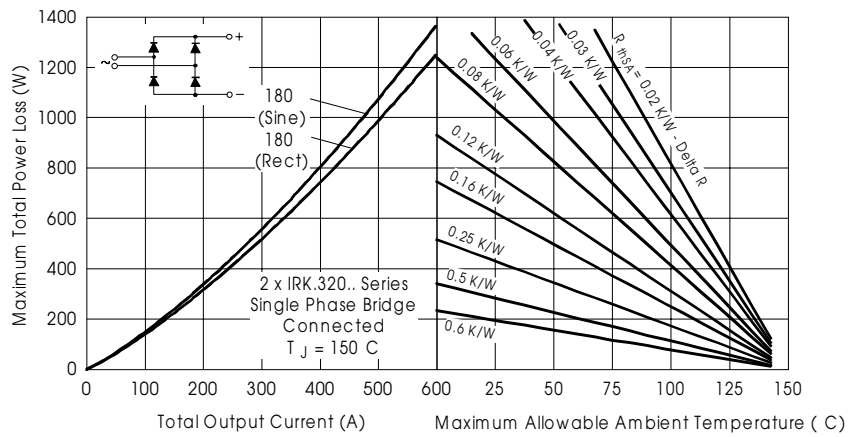


Fig. 28 - Forward Power Loss Characteristics

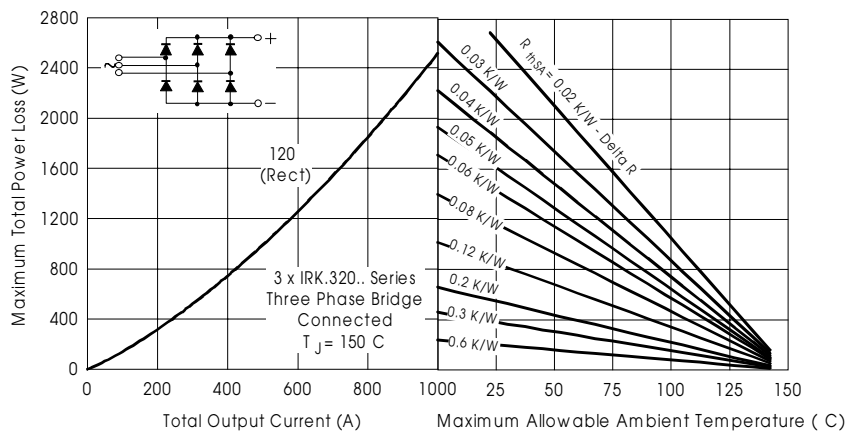


Fig. 29 - Forward Power Loss Characteristics

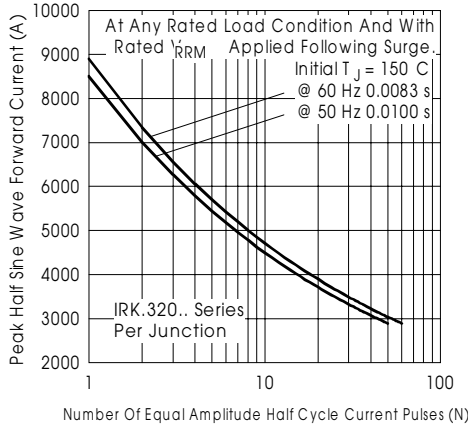


Fig. 30 - Maximum Non-Repetitive Surge Current

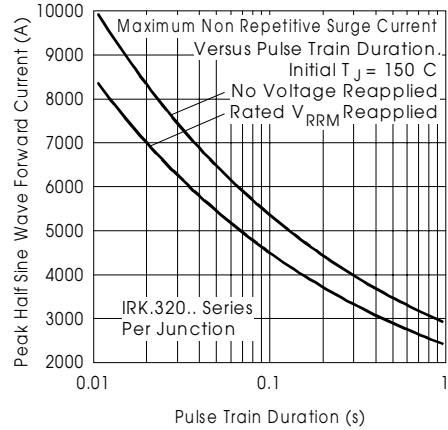


Fig. 31 - Maximum Non-Repetitive Surge Current

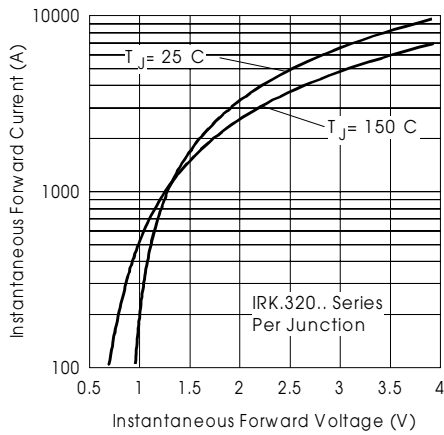


Fig. 32 - Forward Voltage Drop Characteristics

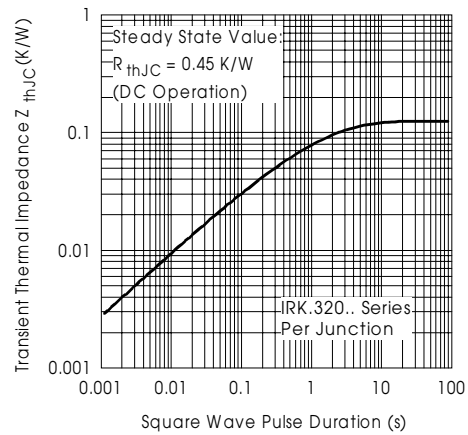


Fig. 33 - Thermal Impedance Z_{thJC} Characteristics

Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.